NSN 5962-01-226-4351

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Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inche	s and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Di	ssipation Rating:
794.0 milliwatts	
Operating Tempura	ture Range:
55.0/+125.0 degree	s celsius
Storage Tempuratu	re Range:
65.0/+150.0 degree	s celsius
End Application:	
An/bps14to15e	
Features Provided:	
lermetically sealed	and burn in and programmable and bipolar and schottky
nclosure Material:	
Ceramic	
nclosure Configura	ition:
Jual-in-line	
Output Logic Form	
Fransistor-transistor	logic
nput Circuit Patter	1:
0 input	
ase Outline Sourc	e And Designator:
D-2 mil-m-38510	
Terminal Surface T	eatment:
Solder	
Voltage Rating And	Type Per Characteristic:
0.5 volts power sou	rce and 7.0 volts power source
Time Rating Per Ch	acteristic:
85.00 nanoseconds	propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Typ	le:
Prom	
Memory Capacity:	
Unknown	
Test Data Documer	t:
96906-mil-std-883 st	andard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And	
16 printed circuit	
Shelf Life:	
N/a	

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

